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Vishay Semiconductors

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## High Speed Infrared Emitting Diodes, 940 nm, **Surface Emitter Technology**





#### **DESCRIPTION**

As part of the SurfLight™ portfolio, the VSMY2940 series are infrared, 940 nm emitting diodes based on GaAlAs surface emitter chip technology with extreme high radiant intensities, high optical power and high speed, molded in clear, untinted plastic packages (with lens) for surface mounting (SMD).

#### **APPLICATIONS**

- · Miniature light barrier
- Photointerrupters
- · Optical switch
- Emitter source for proximity sensors

#### **FEATURES**

 Package type: surface-mount · Package form: GW, RGW



Peak wavelength: λ<sub>p</sub> = 940 nm

- · High reliability
- High radiant power
- · Very high radiant intensity
- Angle of half intensity:  $\varphi = \pm 10^{\circ}$
- · Suitable for high pulse current operation
- · Terminal configurations: gullwing or reverse gullwing
- Package matches with detector VEMD2000X01 series
- Floor life: 4 weeks, MSL 2a, according to J-STD-020
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

PRODUCT SUMMARY					
COMPONENT	I <sub>e</sub> (mW/sr)	φ (deg)	$\lambda_{\mathbf{P}}$ (nm)	t <sub>r</sub> (ns)	
VSMY2940RG	145	± 10	940	10	
VSMY2940G	145	± 10	940	10	

#### Note

Test conditions see table "Basic Characteristics"

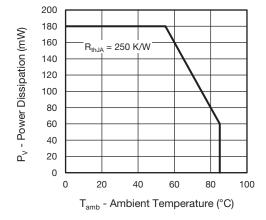
ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VSMY2940RG	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing		
VSMY2940G	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing		

#### Note

· MOQ: minimum order quantity



<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		$V_{R}$	5	V
Forward current		I <sub>F</sub>	100	mA
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I <sub>FM</sub>	200	mA
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	1	A
Power dissipation		P <sub>V</sub>	180	mW
Junction temperature		T <sub>j</sub>	100	°C
Operating temperature range		T <sub>amb</sub>	-40 to +85	°C
Storage temperature range		T <sub>stg</sub>	-40 to +100	°C
Soldering temperature	According to Fig. 10, J-STD-020	T <sub>sd</sub>	260	°C
Thermal resistance junction-to-ambient	J-STD-051, soldered on PCB	R <sub>thJA</sub>	250	K/W



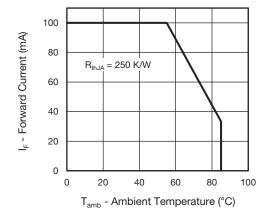


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

Fig. 2 - Forward Current Limit vs. Ambient Temperature

<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Farmend welters	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V <sub>F</sub>	-	1.4	1.8	V
Forward voltage	$I_F = 1 \text{ A}, t_p = 100 \ \mu\text{s}$	V <sub>F</sub>	-	2.5	-	V
Temperature coefficient of V <sub>F</sub>	I <sub>F</sub> = 100 mA	TK <sub>VF</sub>	-	-0.7	-	mV/K
Reverse current		I <sub>R</sub>	Not designed for reverse operation μ		μA	
Junction capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz, E} = 0 \text{ mW/cm}^2$	CJ	-	55	-	pF
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	I <sub>e</sub>	75	145	215	mW/sr
	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	I <sub>e</sub>	-	1000	-	mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фe	-	55	-	mW
Temperature coefficient of radiant power	I <sub>F</sub> = 100 mA	TKφ <sub>e</sub>	-	-0.2	-	%/K
Angle of half intensity		φ	-	± 10	-	deg
Peak wavelength	I <sub>F</sub> = 100 mA	$\lambda_{p}$	920	940	960	nm
Spectral bandwidth	I <sub>F</sub> = 100 mA	Δλ	-	50	-	nm
Temperature coefficient of $\lambda_p$	I <sub>F</sub> = 100 mA	TKλ <sub>p</sub>	-	0.25		nm/K
Rise time	I <sub>F</sub> = 100 mA, 10 % to 90 %	t <sub>r</sub>	-	10	-	ns
Fall time	I <sub>F</sub> = 100 mA, 10 % to 90 %	t <sub>f</sub>	-	10	-	ns

### **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

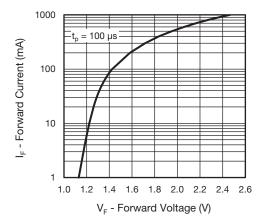


Fig. 3 - Forward Current vs. Forward Voltage

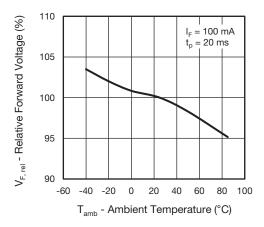


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

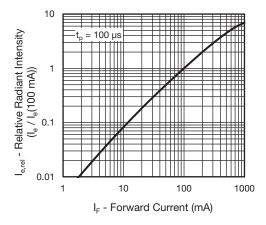


Fig. 5 - Relative Radiant Intensity vs. Forward Current

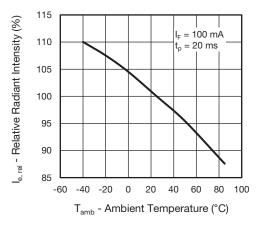


Fig. 6 - Relative Radiant Intensity vs. Ambient Temperature

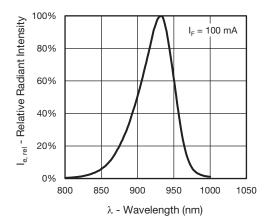


Fig. 7 - Relative Radiant Intensity vs. Wavelength

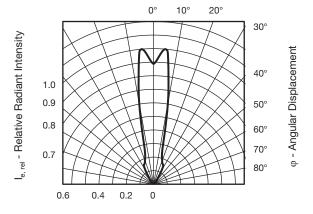


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

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#### **SOLDER PROFILE**

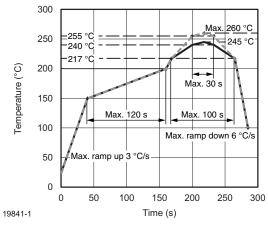


Fig. 9 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020

## Vishay Semiconductors

#### **DRYPACK**

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

#### **FLOOR LIFE**

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 4 weeks

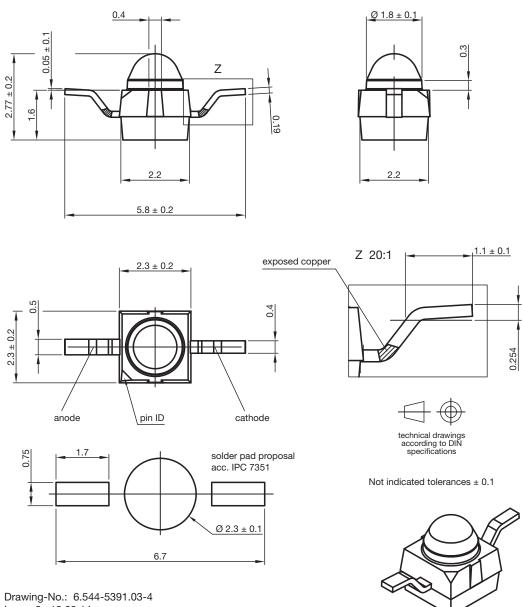
Conditions:  $T_{amb}$  < 30 °C, RH < 60 %

Moisture sensitivity level 2a, according to J-STD-020.

#### **DRYING**

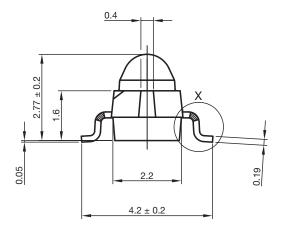
In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

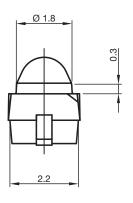
#### PACKAGE DIMENSIONS in millimeters: VSMY2940RG

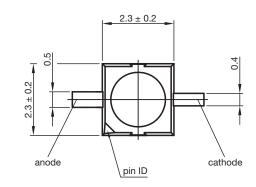


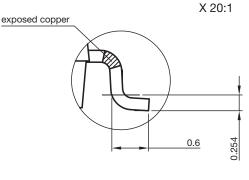
Issue: 2; 19.09.14

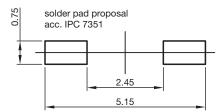
#### PACKAGE DIMENSIONS in millimeters: VSMY2940G





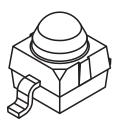








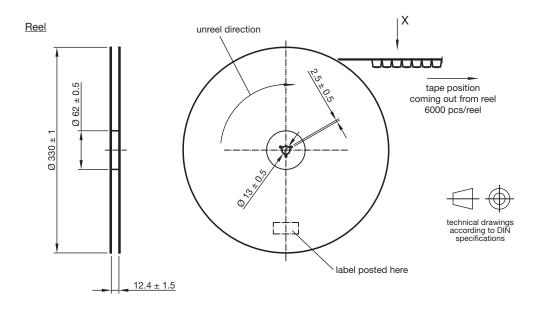
Not indicated tolerances ± 0.1



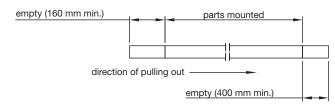
Drawing-No.: 6.544-5383.03-4

Issue: 2; 19.09.14

#### TAPING AND REEL DIMENSIONS in millimeters: VSMY2940RG



#### Leader and trailer tape

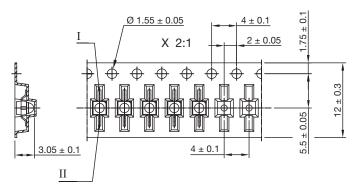


#### Terminal position in tape

Issue: 4; 19.09.14

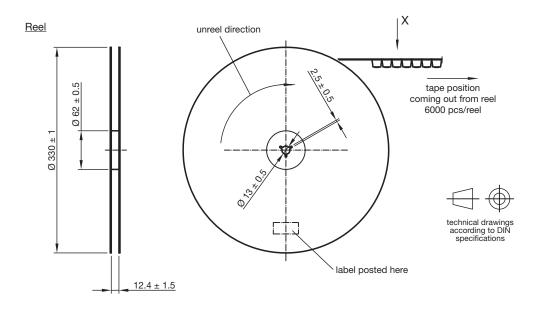
Device	Lead I	Lead II	
VEMT2000	Collector	Emitter	
VEMT2500	Collector	Ellillel	
VEMD2000			
VEMD2500			
VSMB2000	Cathode	Anode	
VSMG2000			
VSMF2890RG			
VSMY2850RG	Anode	Cathode	
VSMY2940RG	Anoue	Califode	

Drawing-No.: 9.800-5100.01-4

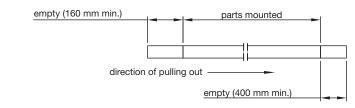




#### TAPING AND REEL DIMENSIONS in millimeters: VSMY2940G

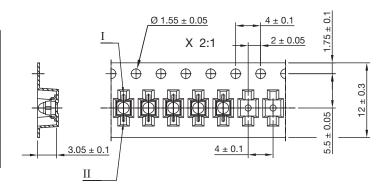


#### Leader and trailer tape



#### Terminal position in tape

Device	Lead I	Lead II	
VSMB2020			
VSMG2020			
VEMD2020	Cathode	Anode	
VEMD2520			
VSMF2890G			
VEMT2020	Collector	Emitter	
VEMT2520	Collector	Emiller	
VSMY2850G	Anode	Cathode	
VSMY2940G	Alloue	Callioue	



Drawing-No.: 9.800-5091.01-4

Issue: 5; 19.09.14



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OSIXCA5121A OSIXCAS1C1A OSM54LZ5D1P OSM5D3Z2C1P OSMR43Z2C1P OSO5PAZ161D OSOR7161D OSPW7161D

OSPW71B1P OSR5PAZE31D OSR9XAE3E1E